TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL PLANER TYPE

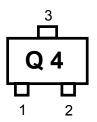
# MT3S37T

VCO OSCILLETOR STAGE UHF LOW NOISE AMPLIFIER APPLICATION

### FEATURES

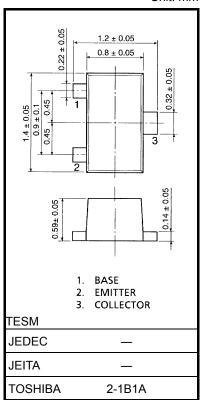
- Low Noise Figure :NF=1.2dB (@f=2GHz)
- High Gain:|S21e|<sup>2</sup>=12.0dB (@f=2GHz)

### Marking



### Absolute Maximum Ratings (Ta = 25°C)

| Characteristics             | Symbol           | Rating  | Unit |
|-----------------------------|------------------|---------|------|
| Collector-Base voltage      | V <sub>CBO</sub> | 8       | V    |
| Collector-Emitter voltage   | V <sub>CEO</sub> | 4.5     | V    |
| Emitter-Base voltage        | V <sub>EBO</sub> | 1.5     | V    |
| Collector-Current           | Ι <sub>C</sub>   | 50      | mA   |
| Base-Current                | Ι <sub>Β</sub>   | 25      | mA   |
| Collector Power dissipation | PC               | 100     | mW   |
| Junction temperature        | Тј               | 150     | °C   |
| Storage temperature Range   | T <sub>stg</sub> | -55~150 | °C   |



Weight:0.0022g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Unit: mm

Microwave Characteristics (Ta = 25°C)

| Characteristics      | Symbol                 | Test Condition                                    | Min | Тур. | Max | Unit |
|----------------------|------------------------|---|-----|------|-----|------|
| Transition Frequency | fT                     | V <sub>CE</sub> =3V, I <sub>C</sub> =20mA, f=2GHz | 15  | 19   | -   | GHz  |
| Insertion Gain       | S21e  <sup>2</sup> (1) | V <sub>CE</sub> =3V, I <sub>C</sub> =20mA, f=1GHz | 15  | 17   | -   | dB   |
|                      | S21e  <sup>2</sup> (2) | V <sub>CE</sub> =3V, I <sub>C</sub> =20mA, f=2GHz | 10  | 12   | -   | dB   |
| Noise Figure         | NF(1)                  | V <sub>CE</sub> =3V, I <sub>C</sub> =3mA, f=1GHz  | -   | 0.9  | -   | dB   |
|                      | NF(2)                  | V <sub>CE</sub> =3V, I <sub>C</sub> =3mA, f=2GHz  | -   | 1.2  | 1.8 | dB   |

### **Electrical Characteristics (Ta = 25°C)**

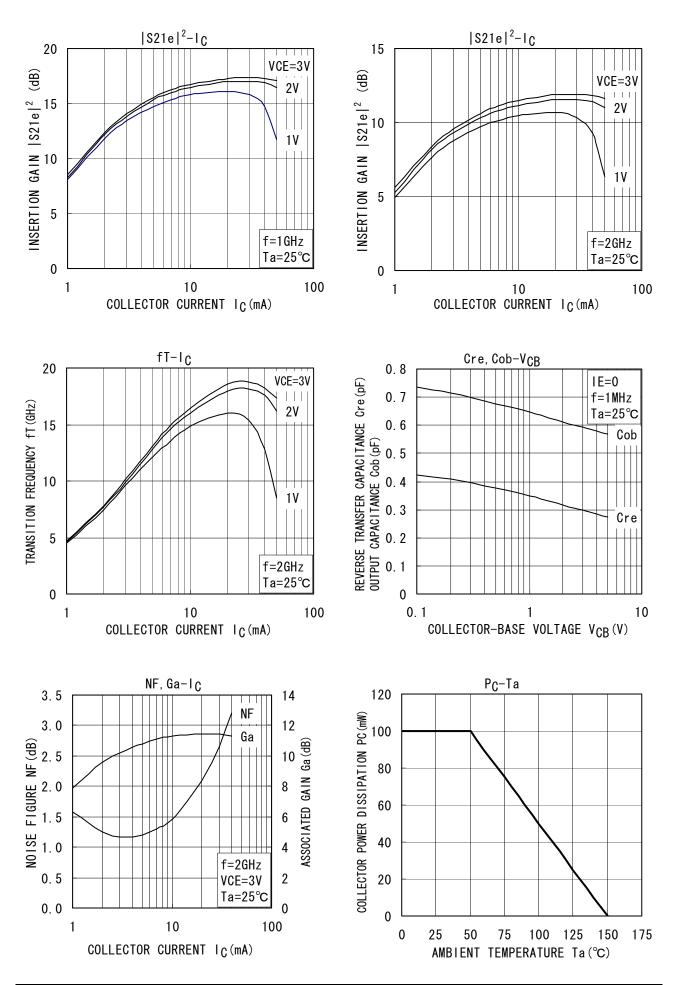
| Characteristics                | Symbol           | Test Condition  | Min | Тур. | Max  | Unit |
|--------------------------------|------------------|---|-----|------|------|------|
| Collector Cut-off Current      | I <sub>CBO</sub> | V <sub>CB</sub> =8V, I <sub>E</sub> =0                  | -   | -    | 1    | μA   |
| Emitter Cut-off Current        | I <sub>EBO</sub> | V <sub>EB</sub> =1V, I <sub>C</sub> =0                  | -   | -    | 1    | μA   |
| DC Current Gain                | hFE              | V <sub>CE</sub> =3V, I <sub>C</sub> =20mA               | 70  | -    | 140  | -    |
| Output Capacitance             | C <sub>ob</sub>  | V <sub>CB</sub> =1V, I <sub>E</sub> =0, f=1MHz          | -   | 0.66 | 1.0  | pF   |
| Reverse Transistor Capacitance | C <sub>re</sub>  | V <sub>CB</sub> =1V, I <sub>E</sub> =0, f=1MHz (Note 1) | -   | 0.35 | 0.65 | pF   |

**Note 1:** Cre is measured by 3 terminal method with capacitance bridge.

**Caution:** This device is sensitive to electrostatic discharge.

Please make enough tool and equipment earthed when you handle.

## **TOSHIBA**



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20070701-EN GENERAL

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